ON Semiconductor

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N-Channel Power MOSFET 620 V, 1.2 Ω

Features

- Low ON Resistance
- Low Gate Charge
- ESD Diode-Protected Gate
- 100% Avalanche Tested
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Rating	Symbol	NDF06N62Z	Unit
Drain-to-Source Voltage	V _{DSS}	620	V
Continuous Drain Current R _{θJC} (Note 1)	I _D	6.0	Α
Continuous Drain Current R ₀ JC, T _A = 100°C (Note 1)	I _D	3.8	Α
Pulsed Drain Current, V _{GS} @ 10 V	I _{DM}	20	Α
Power Dissipation $R_{\theta JC}$	P_{D}	31	W
Gate-to-Source Voltage	V _{GS}	±30	V
Single Pulse Avalanche Energy, I _D = 6.0 A	E _{AS}	113	mJ
ESD (HBM) (JESD 22-A114)	V _{esd}	3000	V
RMS Isolation Voltage (t = 0.3 sec., R.H. ≤ 30%, T _A = 25°C) (Figure 14)	V _{ISO}	4500	V
Peak Diode Recovery (Note 2)	dv/dt	4.5	V/ns
Continuous Source Current (Body Diode)	IS	6.0	Α
Maximum Temperature for Soldering Leads	TL	260	°C
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55 to 150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

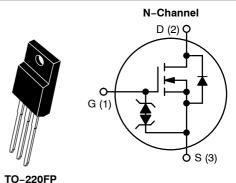
- 1. Limited by maximum junction temperature
- 2. I_{SD} = 6.0 A, $di/dt \le 100$ A/ μ s, $V_{DD} \le BV_{DSS}$, T_J = +150°C



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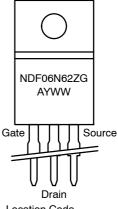
http://onsemi.com

V _{DSS}	R _{DS(ON)} (MAX) @ 3 A
620 V	1.2 Ω



CASE 221D STYLE 1

MARKING DIAGRAM



A = Location Code

Y = Year WW = Work Week

1

G = Pb-Free, Halogen-Free Package

ORDERING INFORMATION

Device	Package	Shipping
NDF06N62ZG	TO-220FP (Pb-Free, Halogen-Free)	50 Units / Rail

THERMAL RESISTANCE

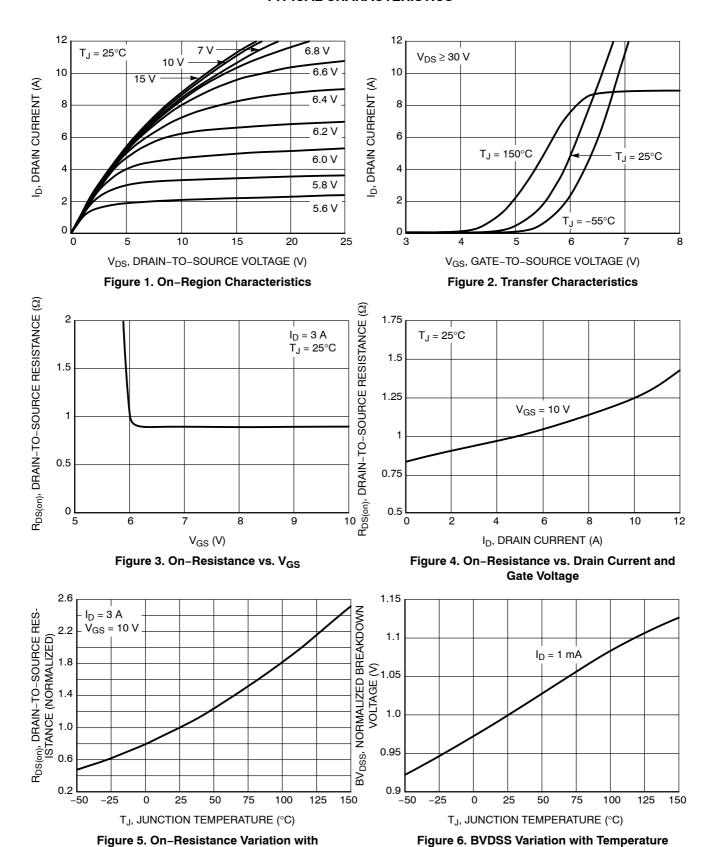
Parameter	Symbol	NDF06N62Z	Unit
Junction-to-Case (Drain)	$R_{ heta JC}$	4.0	°C/W
Junction-to-Ambient Steady State (Note 3)	$R_{\theta JA}$	50	

FLECTRICAL CHARACTERISTICS (T. - 25°C unless otherwise noted)

Characteristic	Test Conditions		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					-	•	
Drain-to-Source Breakdown Voltage	V _{GS} = 0 V, I _D = 1 mA		BV _{DSS}	620			V
Breakdown Voltage Temperature Coefficient	Reference to 25°C, I _D = 1 mA		$\Delta BV_{DSS}/ \Delta T_{J}$		0.6		V/°C
Drain-to-Source Leakage Current	V _{DS} = 620 V, V _{GS} = 0 V	25°C 125°C	I _{DSS}			1 50	μΑ
Gate-to-Source Forward Leakage	V _{GS} = ±20 V	<u> </u>	I _{GSS}			±10	μΑ
ON CHARACTERISTICS (Note 4)					-	•	•
Static Drain-to-Source On-Resistance	V _{GS} = 10 V, I _D = 3.0 A		R _{DS(on)}		0.98	1.2	Ω
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 100 \mu$	A	V _{GS(th)}	3.0		4.5	V
Forward Transconductance	V _{DS} = 15 V, I _D = 3.0 A		9FS		5.0		S
DYNAMIC CHARACTERISTICS					-	•	
Input Capacitance	V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz		C _{iss}		923		pF
Output Capacitance			C _{oss}		106		
Reverse Transfer Capacitance			C _{rss}		23		
Total Gate Charge			Q_g		32		nC
Gate-to-Source Charge	V _{DD} = 310 V, I _D = 6.0 /	Α,	Q _{gs}		6.3		
Gate-to-Drain ("Miller") Charge	V _{GS} = 10 V		Q_{gd}		17		
Plateau Voltage			V _{gp}		6.3		V
Gate Resistance			R_g		3.2		Ω
RESISTIVE SWITCHING CHARACTER	ISTICS						
Turn-On Delay Time			t _{d(on)}		13		ns
Rise Time	V_{DD} = 310 V, I_{D} = 6.0 A, V_{GS} = 10 V, R_{G} = 5 Ω		t _r		19		
Turn-Off Delay Time			t _{d(off)}		32]
Fall Time			t _f		28		
OURCE-DRAIN DIODE CHARACTER	RISTICS (T _C = 25°C unless other	erwise not	ed)				
Diode Forward Voltage	I _S = 6.0 A, V _{GS} = 0 V	H	V_{SD}			1.6	V
Reverse Recovery Time	V _{GS} = 0 V, V _{DD} = 30 V	/	t _{rr}		338		ns
Reverse Recovery Charge	I _S = 6.0 A, di/dt = 100 A/μs		Q _{rr}		2.0		μC

Insertion mounted
 Pulse Width ≤ 380 μs, Duty Cycle ≤ 2%.

TYPICAL CHARACTERISTICS



Temperature

Figure 6. BVDSS Variation with Temperature

TYPICAL CHARACTERISTICS

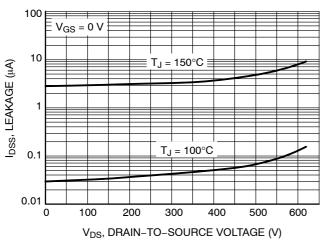


Figure 7. Drain-to-Source Leakage Current vs. Voltage

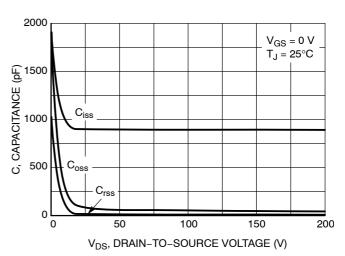


Figure 8. Capacitance Variation

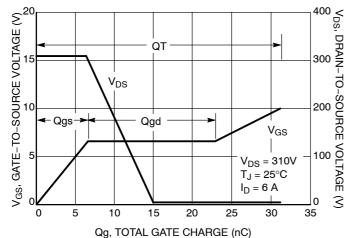


Figure 9. Gate-to-Source and Drain-to-Source Voltage vs. Total Charge

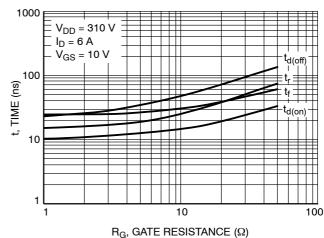


Figure 10. Resistive Switching Time Variation vs. Gate Resistance

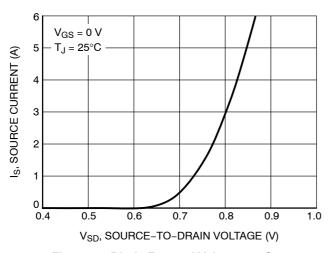


Figure 11. Diode Forward Voltage vs. Current

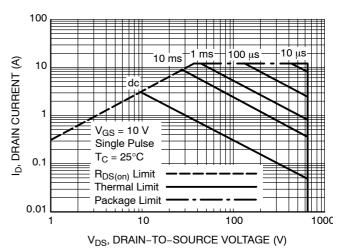


Figure 12. Maximum Rated Forward Biased Safe Operating Area for NDF06N62Z

TYPICAL CHARACTERISTICS

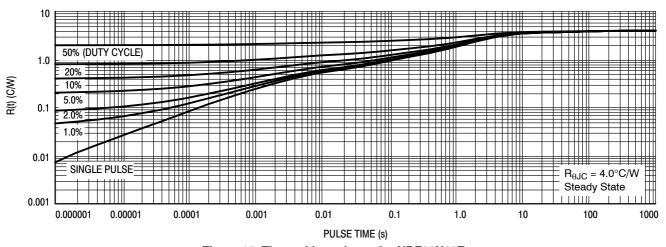


Figure 13. Thermal Impedance for NDF06N62Z

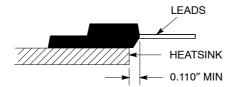


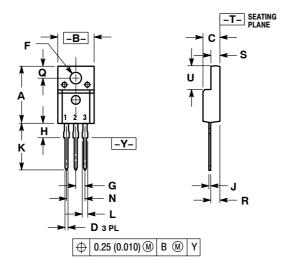
Figure 14. Isolation Test Diagram

Measurement made between leads and heatsink with all leads shorted together.

*For additional mounting information, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

TO-220FP CASE 221D-03 **ISSUE K**



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH
- 221D-01 THRU 221D-02 OBSOLETE, NEW STANDARD 221D-03

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.617	0.635	15.67	16.12	
В	0.392	0.419	9.96	10.63	
С	0.177	0.193	4.50	4.90	
D	0.024	0.039	0.60	1.00	
F	0.116	0.129	2.95	3.28	
G	0.100 BSC		2.54 BSC		
Н	0.118	0.135	3.00	3.43	
J	0.018	0.025	0.45	0.63	
K	0.503	0.541	12.78	13.73	
L	0.048	0.058	1.23	1.47	
N	0.200 BSC		5.08 BSC		
Q	0.122	0.138	3.10	3.50	
R	0.099	0.117	2.51	2.96	
S	0.092	0.113	2.34	2.87	
U	0.239	0.271	6.06	6.88	

PIN 1. GATE

2. DRAIN 3. SOURCE

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